

# 74LV08

## Quad 2-input AND gate

Rev. 03 — 6 April 2009

Product data sheet

## 1. General description

The 74LV08 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC08 and 74HCT08.

The 74LV08 provides a quad 2-input AND function.

## 2. Features

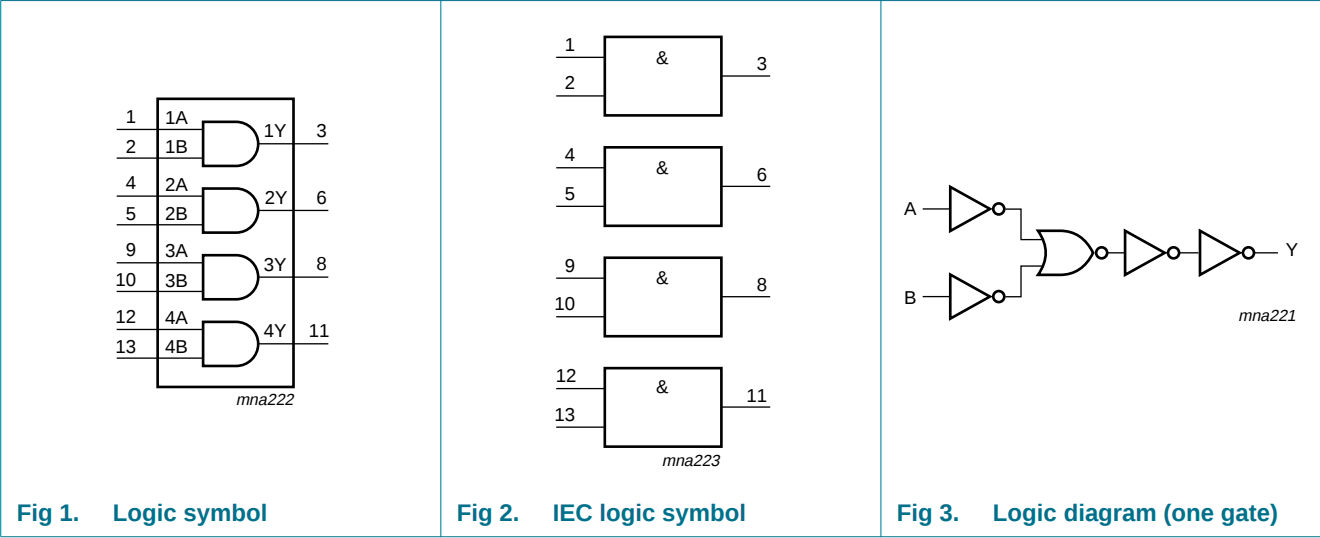
- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between  $V_{CC} = 2.7$  V and  $V_{CC} = 3.6$  V
- Typical output ground bounce < 0.8 V at  $V_{CC} = 3.3$  V and  $T_{amb} = 25$  °C
- Typical HIGH-level output voltage ( $V_{OH}$ ) undershoot: > 2 V at  $V_{CC} = 3.3$  V and  $T_{amb} = 25$  °C
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

## 3. Ordering information

Table 1. Ordering information

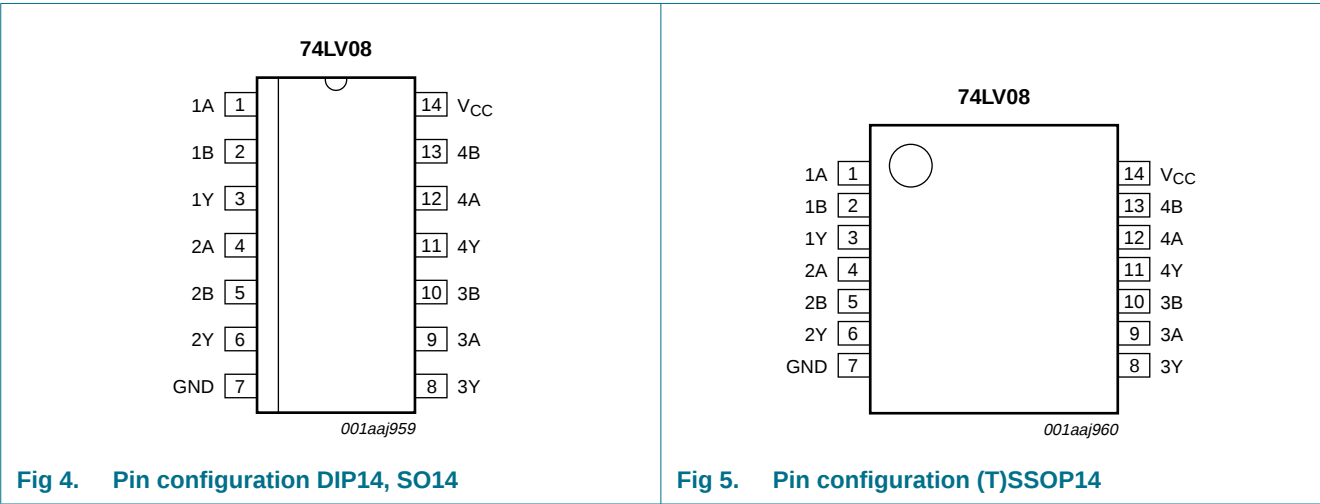
| Type number | Package           |         |                                                                           |          |
|-------------|-------------------|---------|---------------------------------------------------------------------------|----------|
|             | Temperature range | Name    | Description                                                               | Version  |
| 74LV08N     | -40 °C to +125 °C | DIP14   | plastic dual in-line package; 14 leads (300 mil)                          | SOT27-1  |
| 74LV08D     | -40 °C to +125 °C | SO14    | plastic small outline package; 14 leads;<br>body width 3.9 mm             | SOT108-1 |
| 74LV08DB    | -40 °C to +125 °C | SSOP14  | plastic shrink small outline package; 14 leads;<br>body width 5.3 mm      | SOT337-1 |
| 74LV08PW    | -40 °C to +125 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads;<br>body width 4.4 mm | SOT402-1 |

4. Functional diagram



5. Pinning information

5.1 Pinning



## 5.2 Pin description

**Table 2.** Pin description

| Symbol          | Pin          | Description    |
|-----------------|--------------|----------------|
| 1A, 2A, 3A, 4A  | 1, 4, 9, 12  | data input     |
| 1B, 2B, 3B, 4B  | 2, 5, 10, 13 | data input     |
| 1Y, 2Y, 3Y, 4Y  | 3, 6, 8, 11  | data output    |
| GND             | 7            | ground (0 V)   |
| V <sub>CC</sub> | 14           | supply voltage |

## 6. Functional description

**Table 3.** Function selection<sup>[1]</sup>

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | X  | L      |
| X     | L  | L      |
| H     | H  | H      |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care

## 7. Limiting values

**Table 4.** Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                                             | Min              | Max  | Unit |
|------------------|-------------------------|--------------------------------------------------------|------------------|------|------|
| V <sub>CC</sub>  | supply voltage          |                                                        | -0.5             | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ | <sup>[1]</sup> - | ±20  | mA   |
| I <sub>OK</sub>  | output clamping current | $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ | <sup>[1]</sup> - | ±50  | mA   |
| I <sub>O</sub>   | output current          | $V_O = -0.5\text{ V}$ to $(V_{CC} + 0.5\text{ V})$     | -                | ±25  | mA   |
| I <sub>CC</sub>  | supply current          |                                                        | -                | 50   | mA   |
| I <sub>GND</sub> | ground current          |                                                        | -50              | -    | mA   |
| T <sub>stg</sub> | storage temperature     |                                                        | -65              | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C                   | <sup>[2]</sup>   |      |      |
|                  |                         | DIP14 package                                          | -                | 750  | mW   |
|                  |                         | SO14, SSOP14, TSSOP14                                  | -                | 500  | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP14 packages: above 70 °C the value of P<sub>tot</sub> derates linearly with 12 mW/K.  
 For SO14 packages: above 70 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.  
 For (T)SSOP14 packages: above 60 °C the value of P<sub>tot</sub> derates linearly with 5.5 mW/K.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V).

| Symbol              | Parameter                           | Conditions                              | Min | Typ | Max      | Unit |
|---------------------|-------------------------------------|-----------------------------------------|-----|-----|----------|------|
| $V_{CC}$            | supply voltage <sup>[1]</sup>       |                                         | 1.0 | 3.3 | 5.5      | V    |
| $V_I$               | input voltage                       |                                         | 0   | -   | $V_{CC}$ | V    |
| $V_O$               | output voltage                      |                                         | 0   | -   | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                                         | -40 | +25 | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.0\text{ V to }2.0\text{ V}$ | -   | -   | 500      | ns/V |
|                     |                                     | $V_{CC} = 2.0\text{ V to }2.7\text{ V}$ | -   | -   | 200      | ns/V |
|                     |                                     | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$ | -   | -   | 100      | ns/V |
|                     |                                     | $V_{CC} = 3.6\text{ V to }5.5\text{ V}$ | -   | -   | 50       | ns/V |

[1] The static characteristics are guaranteed from  $V_{CC} = 1.2\text{ V}$  to  $V_{CC} = 5.5\text{ V}$ , but LV devices are guaranteed to function down to  $V_{CC} = 1.0\text{ V}$  (with input levels GND or  $V_{CC}$ ).

## 9. Static characteristics

**Table 6. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                 | Conditions                                             | -40 °C to +85 °C |                    |             | -40 °C to +125 °C |             | Unit |
|----------|---------------------------|--------------------------------------------------------|------------------|--------------------|-------------|-------------------|-------------|------|
|          |                           |                                                        | Min              | Typ <sup>[1]</sup> | Max         | Min               | Max         |      |
| $V_{IH}$ | HIGH-level input voltage  | $V_{CC} = 1.2\text{ V}$                                | 0.9              | -                  | -           | 0.9               | -           | V    |
|          |                           | $V_{CC} = 2.0\text{ V}$                                | 1.4              | -                  | -           | 1.4               | -           | V    |
|          |                           | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$                | 2.0              | -                  | -           | 2.0               | -           | V    |
|          |                           | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                | $0.7V_{CC}$      | -                  | -           | $0.7V_{CC}$       | -           | V    |
| $V_{IL}$ | LOW-level input voltage   | $V_{CC} = 1.2\text{ V}$                                | -                | -                  | 0.3         | -                 | 0.3         | V    |
|          |                           | $V_{CC} = 2.0\text{ V}$                                | -                | -                  | 0.6         | -                 | 0.6         | V    |
|          |                           | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$                | -                | -                  | 0.8         | -                 | 0.8         | V    |
|          |                           | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                | -                | -                  | $0.3V_{CC}$ | -                 | $0.3V_{CC}$ | V    |
| $V_{OH}$ | HIGH-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}$                        |                  |                    |             |                   |             |      |
|          |                           | $I_O = -100\text{ }\mu\text{A}; V_{CC} = 1.2\text{ V}$ | -                | 1.2                | -           | -                 | -           | V    |
|          |                           | $I_O = -100\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$ | 1.8              | 2.0                | -           | 1.8               | -           | V    |
|          |                           | $I_O = -100\text{ }\mu\text{A}; V_{CC} = 2.7\text{ V}$ | 2.5              | 2.7                | -           | 2.5               | -           | V    |
|          |                           | $I_O = -100\text{ }\mu\text{A}; V_{CC} = 3.0\text{ V}$ | 2.8              | 3.0                | -           | 2.8               | -           | V    |
|          |                           | $I_O = -100\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | 4.3              | 4.5                | -           | 4.3               | -           | V    |
|          |                           | $I_O = -6\text{ mA}; V_{CC} = 3.0\text{ V}$            | 2.4              | 2.82               | -           | 2.2               | -           | V    |
|          |                           | $I_O = -12\text{ mA}; V_{CC} = 4.5\text{ V}$           | 3.6              | 4.2                | -           | 3.5               | -           | V    |

**Table 6. Static characteristics ...continued**  
 Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions                                                                                | –40 °C to +85 °C |                    |      | –40 °C to +125 °C |      | Unit |
|------------------|---------------------------|-------------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|                  |                           |                                                                                           | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| V <sub>OL</sub>  | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                       |                  |                    |      |                   |      |      |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.2 V                                          | -                | 0                  | -    | -                 | -    | V    |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 2.0 V                                          | -                | 0                  | 0.2  | -                 | 0.2  | V    |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 2.7 V                                          | -                | 0                  | 0.2  | -                 | 0.2  | V    |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 3.0 V                                          | -                | 0                  | 0.2  | -                 | 0.2  | V    |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 4.5 V                                          | -                | 0                  | 0.2  | -                 | 0.2  | V    |
|                  |                           | I <sub>O</sub> = 6 mA; V <sub>CC</sub> = 3.0 V                                            | -                | 0.25               | 0.40 | -                 | 0.50 | V    |
|                  |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 4.5 V                                           | -                | 0.35               | 0.55 | -                 | 0.65 | V    |
| I <sub>I</sub>   | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V                          | -                | -                  | 1.0  | -                 | 1.0  | µA   |
| I <sub>CC</sub>  | supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 5.5 V | -                | -                  | 20.0 | -                 | 40   | µA   |
| ΔI <sub>CC</sub> | additional supply current | per input; V <sub>I</sub> = V <sub>CC</sub> – 0.6 V;<br>V <sub>CC</sub> = 2.7 V to 3.6 V  | -                | -                  | 500  | -                 | 850  | µA   |
| C <sub>I</sub>   | input capacitance         |                                                                                           | -                | 3.5                | -    | -                 | -    | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C.

## 10. Dynamic characteristics

**Table 7. Dynamic characteristics**  
 GND = 0 V; For test circuit see [Figure 7](#).

| Symbol          | Parameter                     | Conditions                                                                                                | –40 °C to +85 °C |                    |     | –40 °C to +125 °C |     | Unit |
|-----------------|-------------------------------|-----------------------------------------------------------------------------------------------------------|------------------|--------------------|-----|-------------------|-----|------|
|                 |                               |                                                                                                           | Min              | Typ <sup>[1]</sup> | Max | Min               | Max |      |
| t <sub>pd</sub> | propagation delay             | nA, nB to nY; see <a href="#">Figure 6</a> <sup>[2]</sup>                                                 |                  |                    |     |                   |     |      |
|                 |                               | V <sub>CC</sub> = 1.2 V                                                                                   | -                | 45                 | -   | -                 | -   | ns   |
|                 |                               | V <sub>CC</sub> = 2.0 V                                                                                   | -                | 15                 | 26  | -                 | 33  | ns   |
|                 |                               | V <sub>CC</sub> = 2.7 V                                                                                   | -                | 11                 | 17  | -                 | 21  | ns   |
|                 |                               | V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF <sup>[3]</sup>                                   | -                | 7                  | -   | -                 | -   | ns   |
|                 |                               | V <sub>CC</sub> = 3.0 V to 3.6 V <sup>[3]</sup>                                                           | -                | 9.0                | 15  | -                 | 19  | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                          | -                | -                  | 11  | -                 | 14  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | C <sub>L</sub> = 50 pF; f <sub>i</sub> = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[4]</sup> | -                | 10                 | -   | -                 | -   | pF   |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

[3] Typical values are measured at nominal supply voltage (V<sub>CC</sub> = 3.3 V).

[4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in µW).

P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> × N + Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where:

f<sub>i</sub> = input frequency in MHz, f<sub>o</sub> = output frequency in MHz

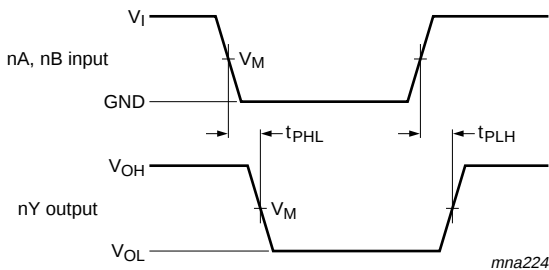
C<sub>L</sub> = output load capacitance in pF

V<sub>CC</sub> = supply voltage in Volts

N = number of inputs switching

Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs.

11. Waveforms

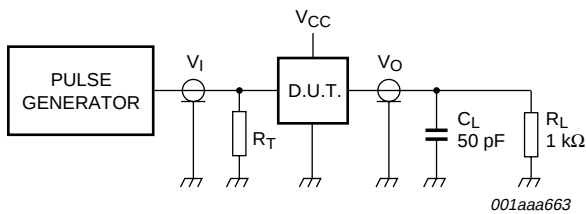


Measurement points are given in [Table 8](#).  
VOL and VOH are typical voltage output levels that occur with the output load.

Fig 6. The input (nA, nB) to output (nY) propagation delays

Table 8. Measurement points

| Supply voltage | Input  | Output |
|----------------|--------|--------|
| VCC            | VM     | VM     |
| < 2.7 V        | 0.5VCC | 0.5VCC |
| 2.7 V to 3.6 V | 1.5 V  | 1.5 V  |
| ≥ 4.5 V        | 0.5VCC | 0.5VCC |



Test data is given in [Table 9](#).  
Definitions test circuit:  
RT = Termination resistance should be equal to output impedance Zo of the pulse generator.  
RL = Load resistance.  
CL = Load capacitance including jig and probe capacitance.

Fig 7. Load circuit for switching times

Table 9. Test data

| Supply voltage | Input | tr, tf   |
|----------------|-------|----------|
| VCC            | VI    |          |
| < 2.7 V        | VCC   | ≤ 2.5 ns |
| 2.7 V to 3.6 V | 2.7 V | ≤ 2.5 ns |
| ≥ 4.5 V        | VCC   | ≤ 2.5 ns |

12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1

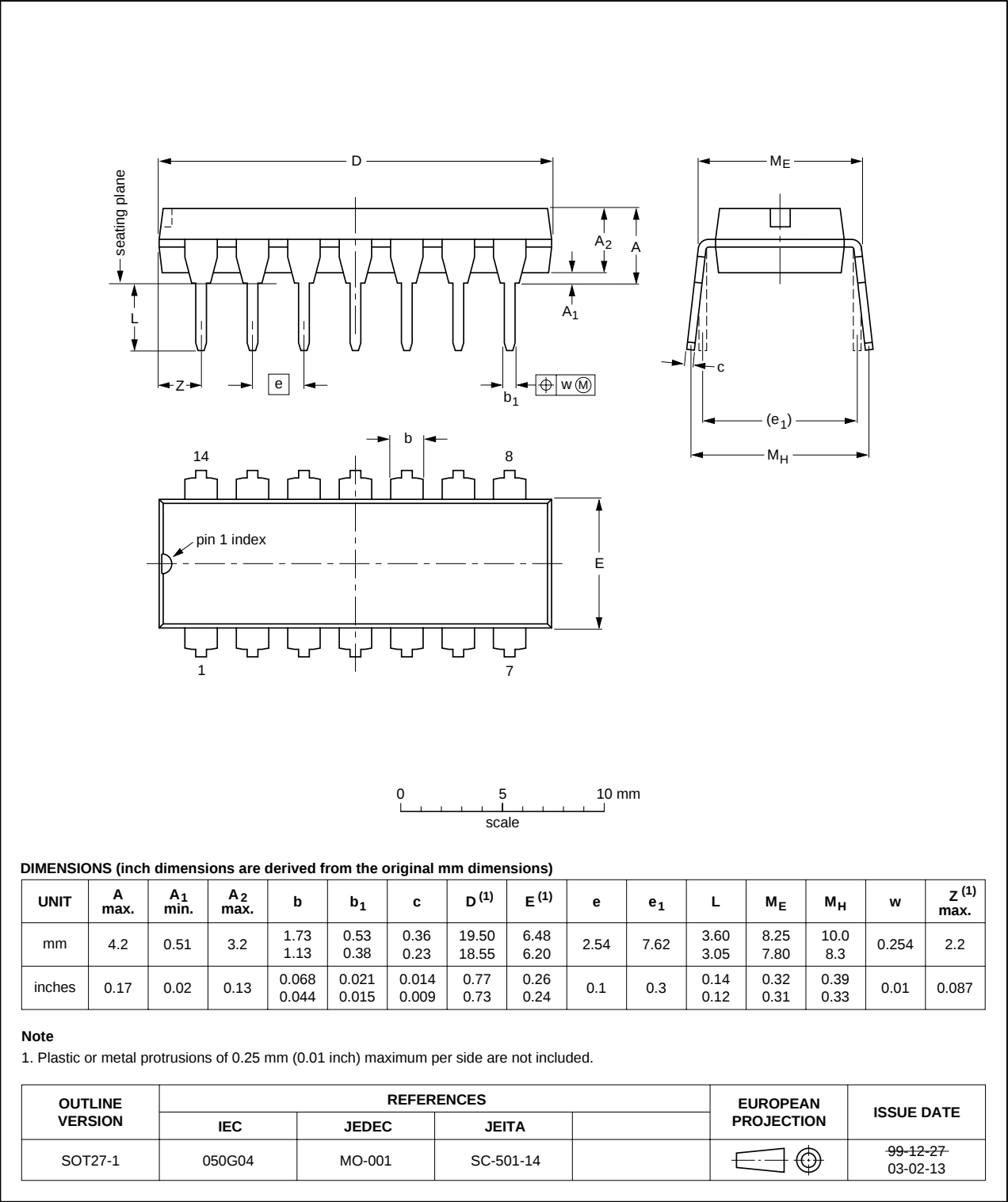


Fig 8. Package outline SOT27-1 (DIP14)

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

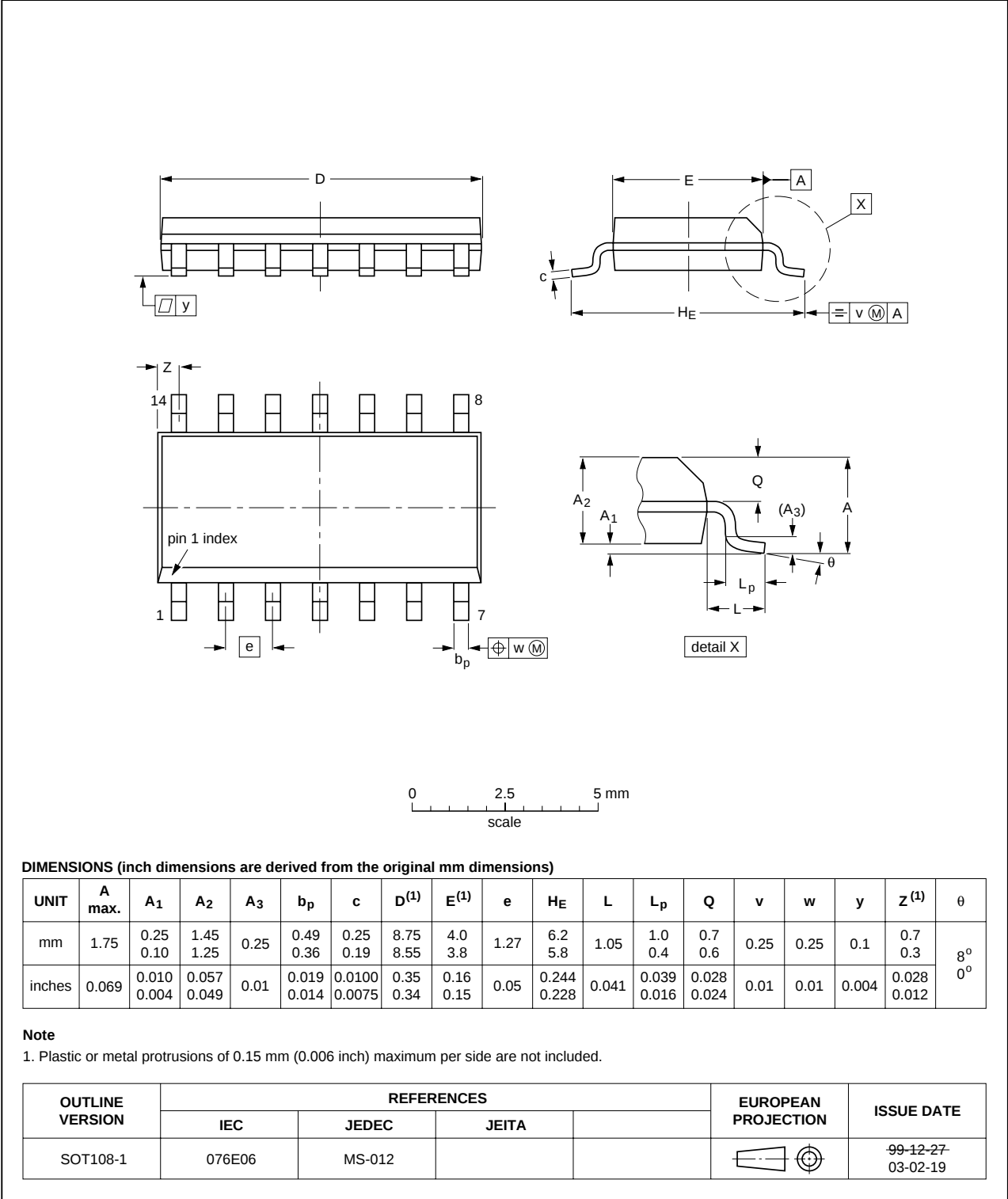


Fig 9. Package outline SOT108-1 (SO14)

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

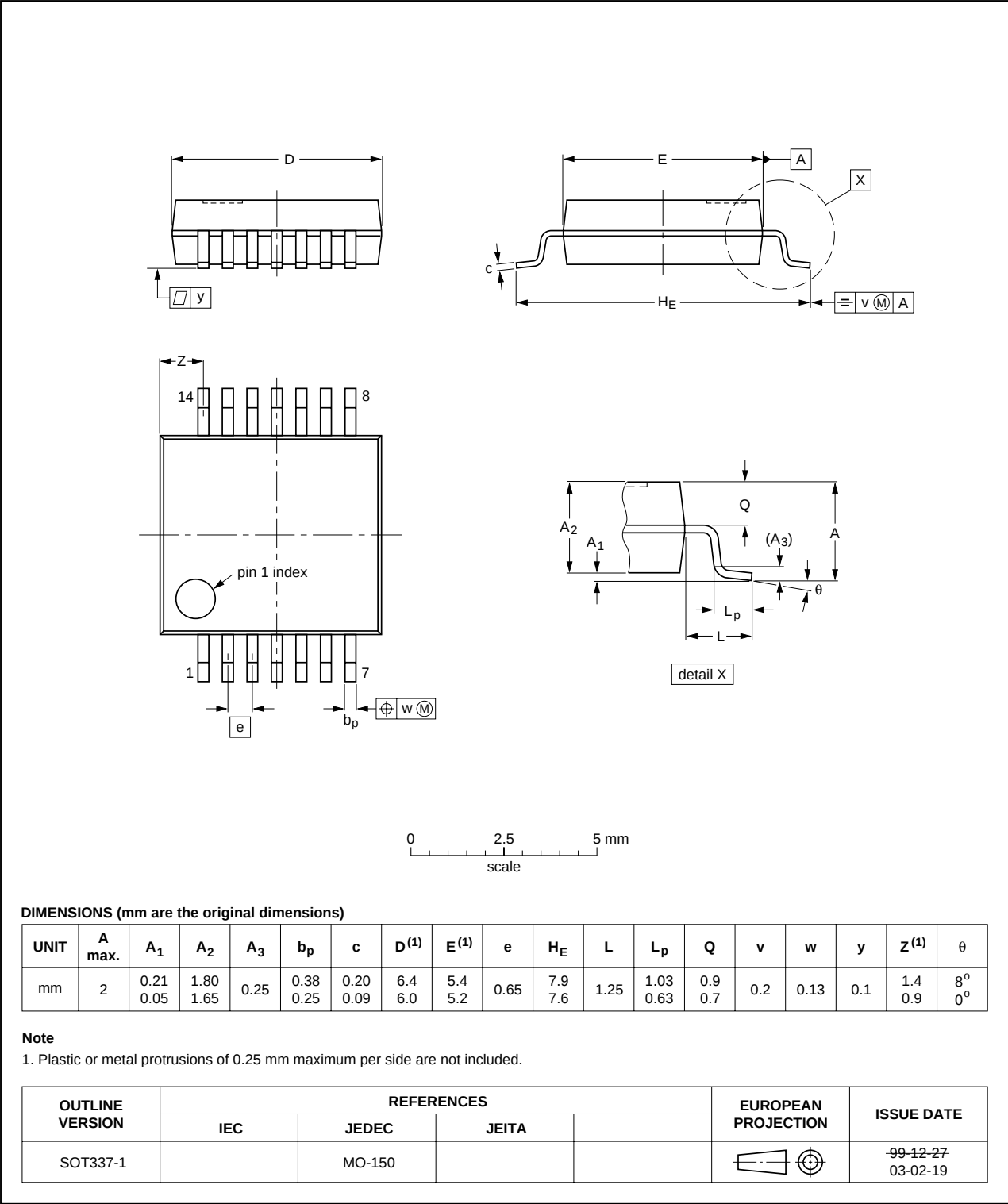


Fig 10. Package outline SOT337-1 (SSOP14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

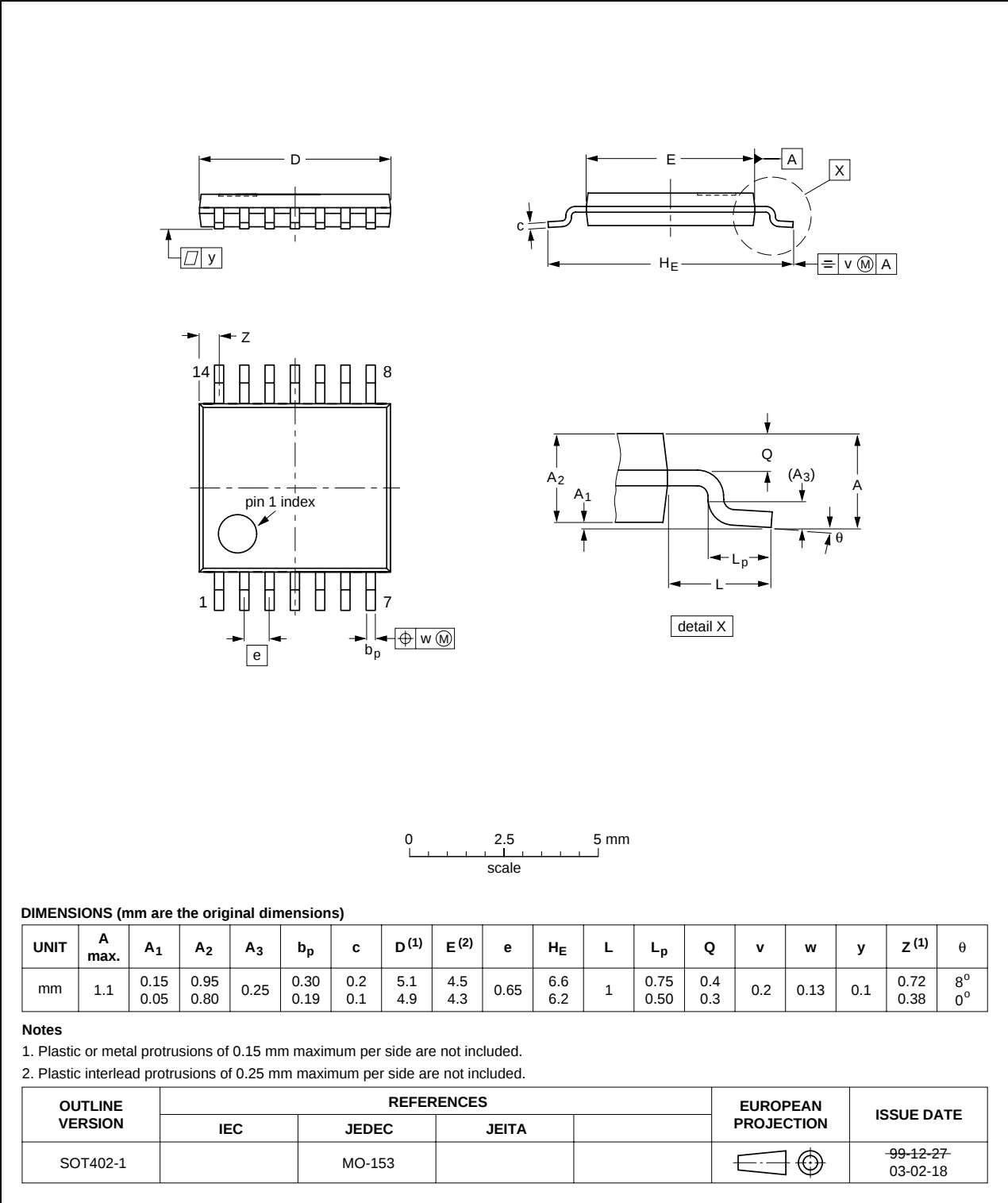


Fig 11. Package outline SOT402-1 (TSSOP14)

## 13. Abbreviations

Table 10. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 14. Revision history

Table 11. Revision history

| Document ID    | Release date                                                                                                                                                                                                                                        | Data sheet status     | Change notice | Supersedes |
|----------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|---------------|------------|
| 74LV08_3       | 20090406                                                                                                                                                                                                                                            | Product data sheet    | -             | 74LV08_2   |
| Modifications: | <ul style="list-style-type: none"><li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>Legal texts have been adapted to the new company name when appropriate.</li></ul> |                       |               |            |
| 74LV08_2       | 19980420                                                                                                                                                                                                                                            | Product specification | -             | 74LV08_1   |
| 74LV08_1       | 19970203                                                                                                                                                                                                                                            | Product specification | -             | -          |

## 15. Legal information

### 15.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

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